PHYS127AL Lecture 6

David Stuart, UC Santa Barbara Transistors and amplifiers

Transistors

A transistor operates by amplifying current. It is *active*, meaning more power out than in. Previous components were *passive*.

Made by sandwiching a thin, lightly-doped p-type layer between n-type regions.

Transistors

If we have a voltage across the base-emitter junction > 0.6 V it becomes forward biased.

Negative charge carries move from the emitter to the base, but they can also move across the field region to the collector.

Transistor rules of operation

- 1). $V_{BE} = 0.6$ V or the transistor is off I.e., $V_B = V_E + 0.6$ V Once the transistor is on, $\Delta V_B = \Delta V_E$.
- 2). $I_C = \beta I_B$. And by charge conservation $I_E = I_B + I_C$ so $I_E \cong I_C$

3). $V_{CE} > 0.2 V$

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Some terminology:

The power supply connected to the collector is called V_{CC} . The power supply connected to the emitter is called V_{EE} .

2N3904

E B C

 $\mathcal{C}_{0}^{(n)}$

 $B -$

view

 E^{\parallel} E^{BC}

Simplest transistor circuit

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The benefit here is <u>increased input impedance</u>. Recall that impedance is $R = \Delta V/\Delta I$

Without the transistor we need to flow $\Delta I = \Delta V / R_E$ to change V_{in} by ΔV

With the transistor, we can calculate R_{in} from

 $R_{in} = \Delta V_{in} / \Delta I_{in} = \Delta V_{B} / \Delta I_{B}$

The base current is $1/\beta$ of the emitter current, since $I_E \cong I_C = \beta I_B$. So,

 $R_{in} = \Delta V_{in} / \Delta I_{in} = \Delta V_{B} / (\Delta I_{E} / \beta) = \beta \Delta V_{B} / \Delta I_{E}$

We also had from the transistor rules that $V_B = V_E + 0.6$, so $\Delta V_B = \Delta V_E$, so

 $R_{in} = \beta \Delta V_B / \Delta I_E = \beta \Delta V_E / \Delta I_E = \beta R_E$

The input impedance is β times larger than R_E. The transistor amplifies the impedance by $\beta \approx 100$. RE

 $\rm V_E$ o

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This is the way to make each stage have large input impedance; put a transistor at its input.

The emitter will follow the *variations* in the input. The DC shift of 0.6 V is not a problem because *the variation of Vin is the signal*.

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Can get a factor of β^2 with two followers. (Darlington configuration.) However, that costs two diode drops.

We can remove the clipping at $0 \vee y$ setting V_{EE} to a negative supply.

Output clips at V_{CC} and 0.6 V above V_{EE} .

We can use the current amplification of the transistor to get voltage amplification.

 V_{CC} = + 5 V V_{EE} = - 5 V RE Vout V_{in} o RC

The input and output are with respect to ground, but we don't really need to show ground here. The transistor only cares about relative voltage differences.

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The signal is ΔV_{in} not just the value of V_{in} . So we want to calculate both V_{out} and ΔV_{out} . First we'll do the DC part, V_{in} , then the AC part, ΔV_{in} .

$$
? \qquad \qquad
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 $V_E = ?$ and $\Delta V_E = ?$

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$$

\n
$$
V_{out} = V_{CC} - I_{C}R_{C} \approx V_{CC} - I_{E}R_{C}.
$$
 Because $I_{E} = I_{B} + I_{C} \& I_{E} \approx I_{C}$
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 $Gain = \Delta V_{out} / \Delta V_{in} = - R_C / R_E$

Negative gain OK for music. Choose amplification by choosing resistance values.

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 $Gain = \Delta V_{out} / \Delta V_{in} = -R_C/R_E$

Negative gain OK for music. Choose amplification by choosing resistance values.

We want an amplifier stage that doesn't need the previous stage to carefully adjust the offset voltage to avoid clipping. So build it in.

 V_{CC} = + 5 V V_{EE} = - 5 V RE $\rm V_{out}$ Vin R_C E B $\mathcal{C}_{0}^{(n)}$

Apply an "input bias" that puts the emitter close to V_{EE} , within a ΔV that defines the max input swing.

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Suppose I want a max input swing of ± 0.1 V Set V_E to vary from -4.8 to -5.0, i.e., DC set point for V_E is -4.9 V. DC set point for V_{in} is -4.3 V. These are called the *quiescent* values, meaning "when quiet, ie without signal".

Choose R_1 and R_2 to be a voltage divider setting V_{in} at -4.3 V.

 $V_{in} = V_{EE} + (V_{CC} - V_{EE}) * R_2 / (R_1 + R_2)$ $-4.3 = -5 + 10*1k/(1k+R_2)$ $R_1 = 13k$ and $R_2 = 1k$ Or I could use $R_1 = 130k$ and $R_2 = 10k$ Which choice is better?

Apply an input bias that puts the emitter close to V_{EE} , within a ΔV that defines the max input swing.

Suppose I want a max input swing of ± 0.1 V Set quiescent points: V_E =-4.9 V & V_{in} =-4.3 V. $R_1 = 130k$ and $R_2 = 10k$

But now this stage yanks the output of the previous stage to a different voltage. Fix that by *decoupling* the input from this "DC bias voltage" with a "decoupling capacitor".

RinCin make a high-pass filter letting the signal through and blocking the DC offsets. What is R_{in}?

Apply an input bias that puts the emitter close to V_{EE} , within a ΔV that defines the max input swing.

Input impedance is all paths from input to a fixed voltage (V_{CC} , V_{EE} , or Gnd).

 $R_{in} = R_1 \parallel R_2 \parallel \beta R_E \cong 130k \parallel 10k \parallel \beta R_E \cong R_2$.

High-pass filter should have f_{3dB} signal frequency range.

For audio signals, that is 20 Hz, so

 $20 = 1/2\pi(10k)C$

 $C \approx 1/6*120*10k \approx 1/1k*10k = 0.1 \mu F$

Now we need to pick R_E and R_C

The ratio of R_E and R_C is set by the desired gain, and avoiding output clipping.

Choose gain $= 10$. That means Vout swings by ± 1 V. Then quiescent point for V_{out} to be at least 1 V away from V_{CC} and V_{E} . But,

 $V_{\text{out}} = V_{\text{CC}} - V_{\text{E}}(R_{\text{C}}/R_{\text{E}}) + V_{\text{EE}}(R_{\text{C}}/R_{\text{E}})$ only depends on the gain ratio.

$$
V_{\text{out}} = 5 - (-4.9 * 10) - 5 * 10
$$

= 4

That works, but just barely.

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The challenge here is that R_E affects both the gain and the quiescent V_{out} . A small R_E gives big gain but large I_E which affects quiescent V_{out} .

We want a large R_E for setting quiescent voltages and a small RE for setting gain.

The challenge here is that R_E affects both the gain and the quiescent V_{out} . A small R_E gives big gain but large I_E which affects quiescent V_{out} .

We want a large R_E for setting DC quiescent voltages and a small R_E for setting AC gain.

Finally, what can we do about the 1 V quiescent offset on V_{out} ?

This all works if V_{EE} is ground. We just have to choose quiescent points. In fact with V_{EE}=Gnd, we *must* have input biasing.

Some checks of understanding.

 V_{CC} = + 5 V $\rm V_{EE}$ R_E Vout V_{in} o RC $R₂$ R_1 C_{in} C_g $\rm R_G$ C_{out}

Without DC biasing, what would limit the signal?

What is the output impedance of this circuit?

What would happen if you set $R_G = 0$?

With $V_{EE} = Gnd$, about where should you put the quiescent V_{out} ? Where is the quiescent V_{in} ? In general, how do you maximize the *dynamic range*?

Common-emitter amplifier operation

The transistor is changing the voltage dropped across it to satisfy the rules of operation.

Increase in V_{in} causes increase in V_{E} That causes an increase in I_E That causes a decrease in V_C The voltage across the transistor, V_{CE} , goes down to compensate.